

#11/AMOT  
C  
(NE)  
9/23/03  
vs

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

**In re Application of**

Bojarczuk, et al.

**Serial No.:** 09/755,164

**Group Art Unit:** 2826

**Filed:** January 8, 2001

**Examiner:** Quinto, Kevin V.

**For:** ALUMINUM NITRIDE AND ALUMINUM OXIDE/ALUMINUM NITRIDE  
HETEROSTRUCTURE GATE DIELECTRIC STACK BASED FIELD EFFECT  
TRANSISTORS AND METHOD FOR FORMING SAME

Honorable Commissioner of Patents  
Box AF  
Alexandria, VA 22313 - 1450

**AMENDMENT AFTER FINAL REJECTION UNDER 37 C.F.R. §1.116**

Sir:

In preparation for imminent appeal and in response to the Office Action dated July 16, 2003, please amend the above-identified application as follows:

**INTRODUCTORY COMMENTS**

Claims 1-7 and 14-18 are all the claims presently pending in the application. Claims 1-7, 14-15 and 17 have been amended to more clearly define the invention. Claims 1, 14-15 and 17 are independent.